UMW SM4027PSU

-40V P-Channel MOSFET

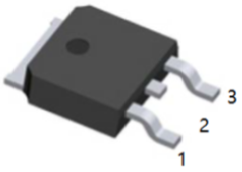
1.Features

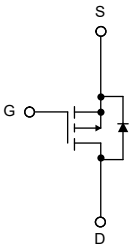
- $V_{DS\ (V)}$=-40V
- $R_{DS(ON)}$<17mΩ(V_{GS}=-10V)
- $R_{DS(ON)}$<29mΩ(V_{GS}=-4.5V)
- Package with low thermal resistance

2.Pinning information

Pin	Symbol	Description
1	G	GATE
2	D	DRAIN
3	S	SOURCE

TO-252(DPAK)
top view





3.Absolute Maximum Ratings T_C= 25°C

Parameter		Symbol	Value	Units
Drain-Source Voltage		V_{DS}	-40	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Current	T_C=25°C [a]	I_D	-50	A
	T_C=125°C		-39	
Continuous Source Current (Diode Conduction) [a]		I_S	-50	
Pulsed Drain Current [b]		I_{DM}	-200	
Single Pulse Avalanche Current	L=0.1mH	I_{AS}	-40	
Single Pulse Avalanche Energy	L=0.1mH	E_{AS}	80	mJ
Maximum Power Dissipation [b]	T_A=25°C	P_D	3	W
	T_C=25°C		136	W
	T_A=125°C		45	W
Junction and Storage Temperature Range		T_J,T_{STG}	-55 to 175	°C

4.Thermal Resistance Rating

Parameter		Symbol	LIMIT	Units
Junction-to-Ambient	PCB Mount [c]	R_{thJA}	50	°C/W
Junction-to-Case (Drain)		R_{thJC}	1.1	°C/W

Notes

a. Package limited.

b. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %.

c. When mounted on 1" square PCB (FR4 material).

d. Parametric verification ongoing.

5.Specifications (T_C= 25°C, unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static						
Drain-Source Breakdown Voltage	V_{DS}	V_{GS}=0V, I_D=-250μA	-40			V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=-250μA	-1.5		-2.5	V
Gate-Body Leakage	I_{GSS}	V_{GS}=±20V, V_{DS}=0V			±100	nA
Zero gate voltage drain current	I_{DSS}	V_{DS}=-40V,V_{GS}=0V			-1	μA
		V_{DS}=-40V,V_{GS}=0V,T_J=125°C			-50	μA
		V_{DS}=-40V,V_{GS}=0V,T_J=175°C			-150	μA
On-State Drain Current [a]	$I_{D(ON)}$	V_{DS}≤-5V, V_{GS}=-10V	-50			A
Drain-Source On-State Resistance [a]	$R_{DS(ON)}$	V_{GS}=-10V, I_D=-17A			17	mΩ
		V_{GS}=-4.5V, I_D=-14A			29	mΩ
Forward Transconductance [a]	g_{FS}	V_{DS}=-15V, I_D=-17A		61		S
Dynamic [b]						
Input Capacitance	C_{iss}	V_{GS}=0V, V_{DS}=-25V, f=1MHz		2872	3950	pF
Output Capacitance	C_{oss}			508	635	pF
Reverse Transfer Capacitance	C_{rss}			352	440	pF
Total Gate Charge [c]	Q_g	V_{DS}=-30V, V_{GS}=-10V, I_D=-50A		60	80	nC
Gate-Source Charge [c]	Q_{gs}			5.7	8.6	nC
Gate-Drain Charge [c]	Q_{gd}			14.7	22	nC
Gate Resistance	R_G	f=1MHz	1.5	3	4.5	Ω
Turn-On Delay Time [c]	$t_{D(on)}$	V_{DD}=-20V, R_L=0.4Ω, I_D≅-50A, V_{GEN}=-10V, R_G=1Ω		10	15	ns
Rise Time [c]	t_r			12	18	ns
Turn-Off Delay Time [c]	$t_{D(off)}$			40	60	ns
Fall Time [c]	t_f			16	24	ns

Source-Drain Diode Ratings and Characteristics [b]						
Pulsed Current [a]	I_{SM}				-200	A
Forward Voltage	V_{SD}	I_F=-50A, V_{GS}=0V		-1	-1.5	V

Notes:

a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

6.1Typical Characterisitics

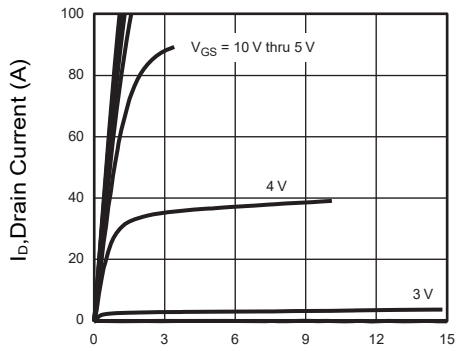


Figure 1: Output Characteristics

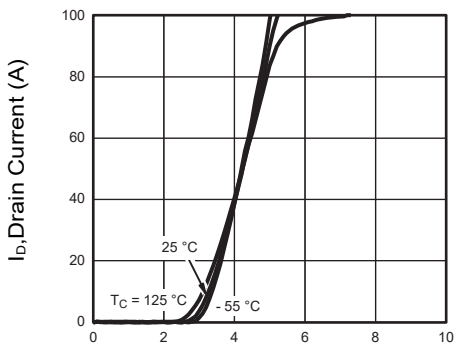


Figure 2: Transfer Characteristics

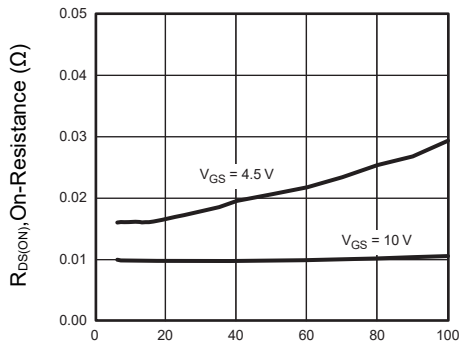


Figure 3: On-Resistance vs. Drain Current

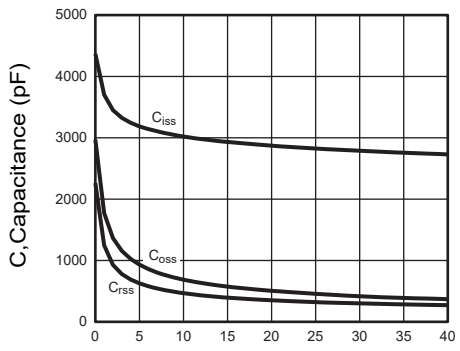


Figure 4: Capacitance

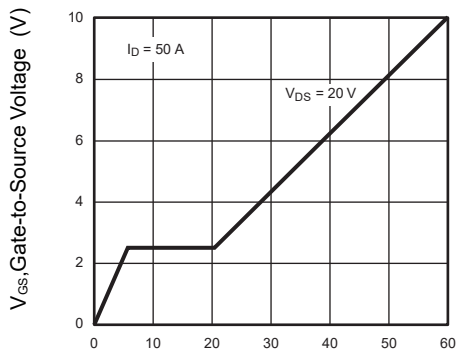


Figure 5: Gate Charge

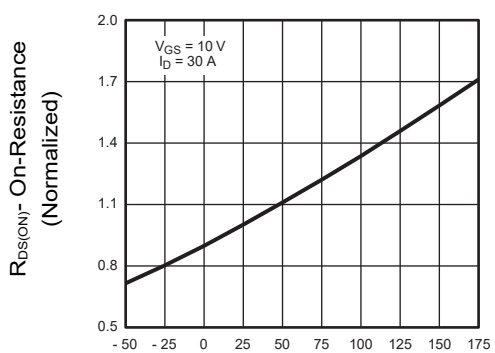


Figure 6: On-Resistance vs. Junction Temperature

6.2Typical Characterisitics

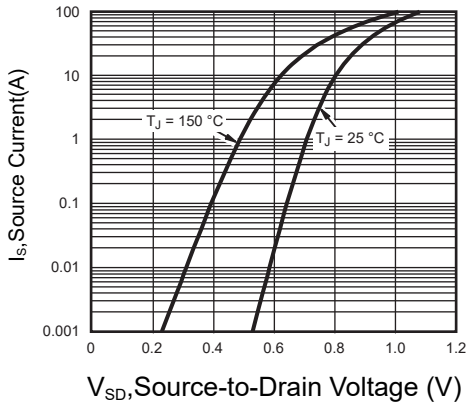


Figure 7: Source-Drain Diode Forward Voltage

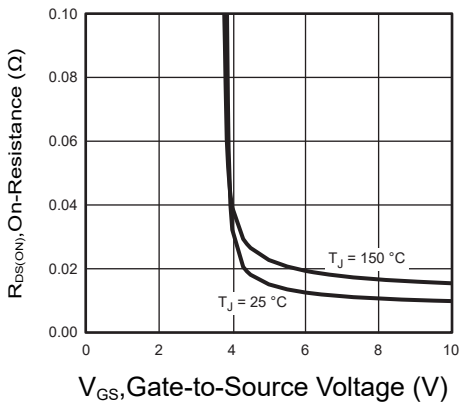


Figure 8: On-Resistance vs. Gate-to-Source Voltage

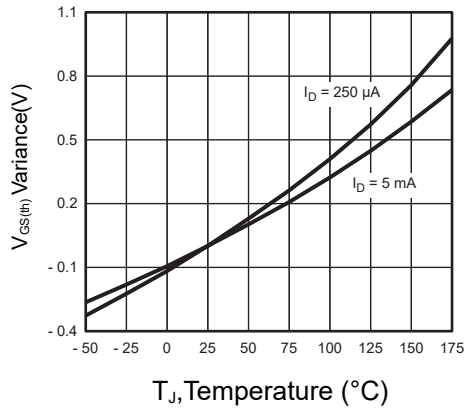


Figure 9: Threshold Voltage

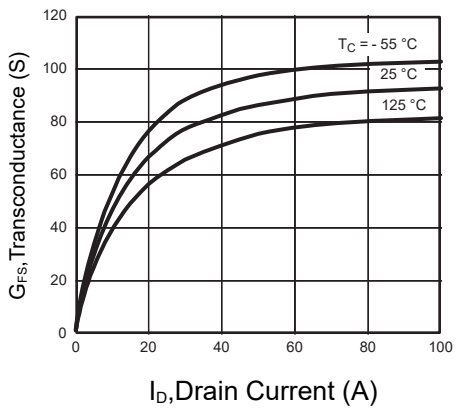


Figure 10: Transconductance

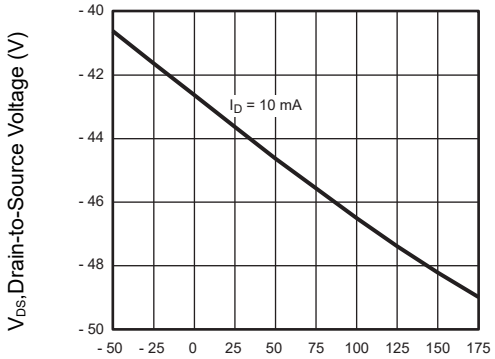
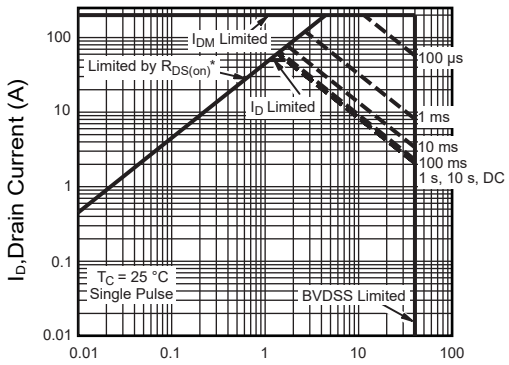


Figure 11: Drain Source Breakdown vs. Junction Temperature

6.3Typical Characterisitics



V_{DS},Drain-to-Source Voltage (V) * V_{GS} > minimum V_{GS} at which $R_{DS(ON)}$ is specified

Figure 12: Safe Operating Area

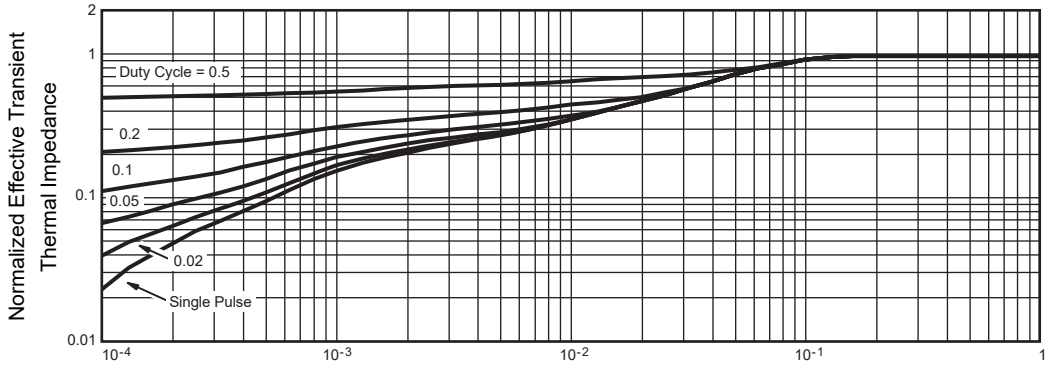


Figure 13: Normalized Thermal Transient Impedance, Junction-to-Case

6.4Typical Characterisitics

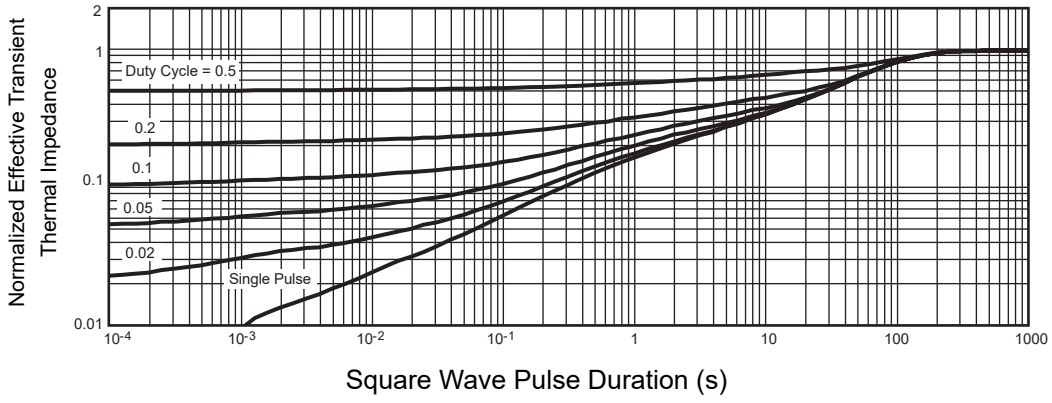


Figure 14: Normalized Thermal Transient Impedance, Junction-to-Ambient

Note:

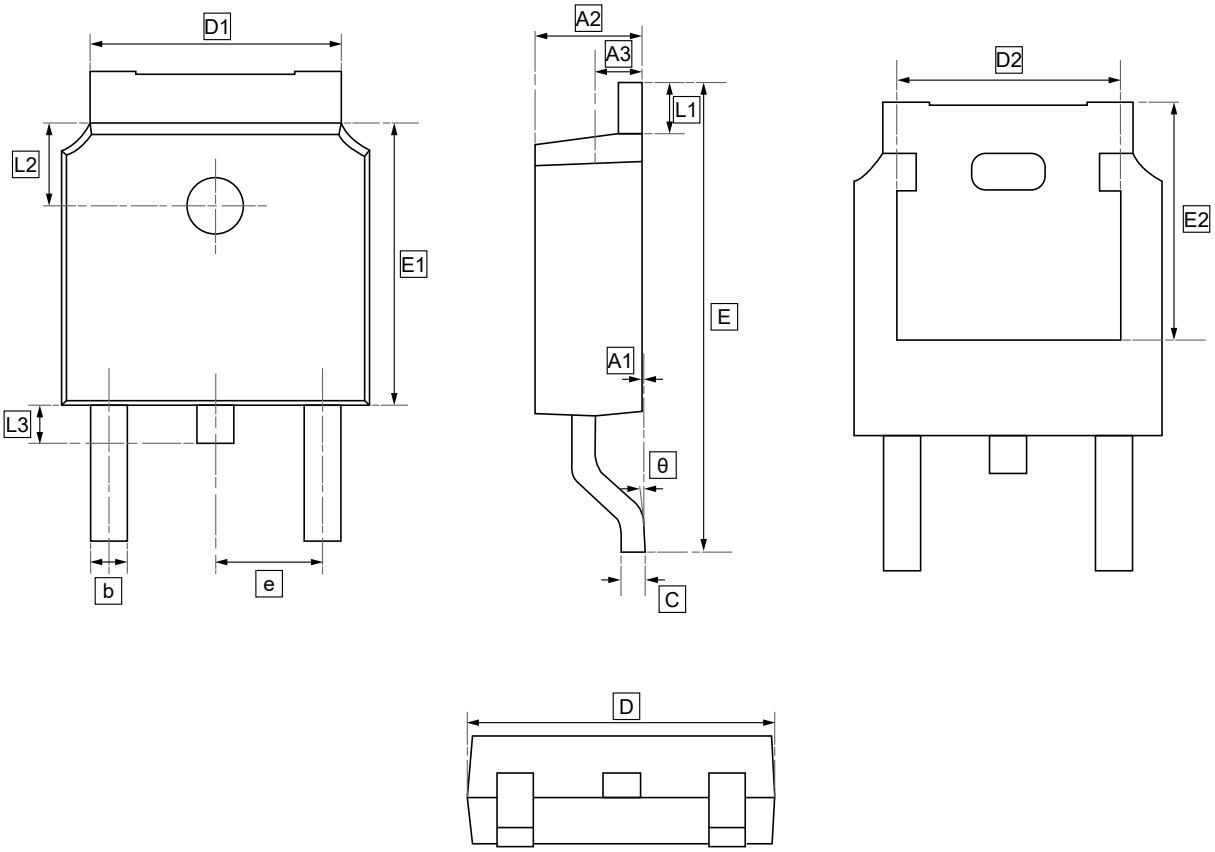
The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

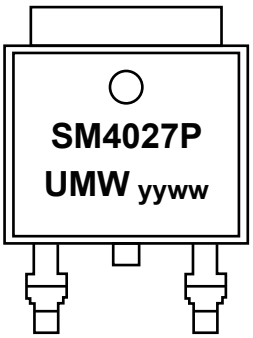
7.TO-252 Package Outline Dimensions



DIMENSIONS (mm are the original dimensions)

Symbol	A1	A2	A3	b	c	D	D1	D2	E	E1	E2	e	L1	L2	L3	θ
Min	0.00	2.18	0.90	0.65	0.46	6.35	4.95	4.32	9.40	5.97	5.21	2.286	0.89	1.70	0.60	0.00
Max	0.13	2.39	1.10	0.85	0.61	6.73	5.46	4.90	10.41	6.22	5.38	BSC	1.27	1.90	1.00	8.00

8.Ordering information



yy: Year Code
ww: Week Code

Order Code	Package	Base QTY	Delivery Mode
UMW SM4027PSU	TO-252	2500	Tape and reel

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